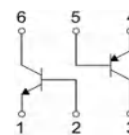




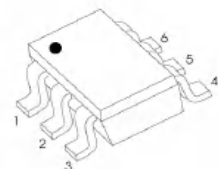
BC847PN Plastic-Encapsulate Transistors

DUAL TRANSISTOR (NPN+PNP)



FEATURES

- Epitaxial Die Construction
- Two isolated NPN/PNP(BC847W+BC857W) Transistors in one package



MAKING: 7P

MAXIMUM RATINGS TR1 ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

SOT-363

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	50	V
V_{CEO}	Collector-Emitter Voltage	45	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current –Continuous	0.1	A
P_C	Collector Power Dissipation	200	mW
T_J	Junction Temperature	150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-55-150	$^{\circ}\text{C}$

CHARACTERISTICS of TR1 (NPN Transistor) ($T_a=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0$	50			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=10\text{mA}, I_B=0$	45			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=1\mu\text{A}, I_C=0$	6			V
Collector cut-off current	I_{CBO}	$V_{CB}=30\text{V}, I_E=0$			15	nA
Emitter cut-off current	I_{EBO}	$V_{EB}=5\text{V}, I_C=0$			15	nA
DC current gain	h_{FE}	$V_{CE}=5\text{V}, I_C=2\text{mA}$	200		450	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$			0.25	V
	$V_{CE(sat)}$	$I_C=100\text{mA}, I_B=5\text{mA}$			0.6	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$		0.7		V
	$V_{BE(sat)}$	$I_C=100\text{mA}, I_B=5\text{mA}$		0.9		V
Base-emitter voltage	$V_{BE(on)}$	$V_{CE}=5\text{V}, I_C=2\text{mA}$	0.58		0.7	V
	$V_{BE(on)}$	$V_{CE}=5\text{V}, I_C=10\text{mA}$			0.72	V
Collector output capacitance	C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$			6.0	pF
Transition frequency	f_T	$V_{CE}=5\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	100			MHz
Noise figure	NF	$V_{CE}=5\text{V}, I_C=0.2\text{mA},$ $f=1\text{kHz}, R_g=2\text{K}\Omega, \Delta f=200\text{Hz}$			10	dB



MAXIMUM RATINGS TR2 ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

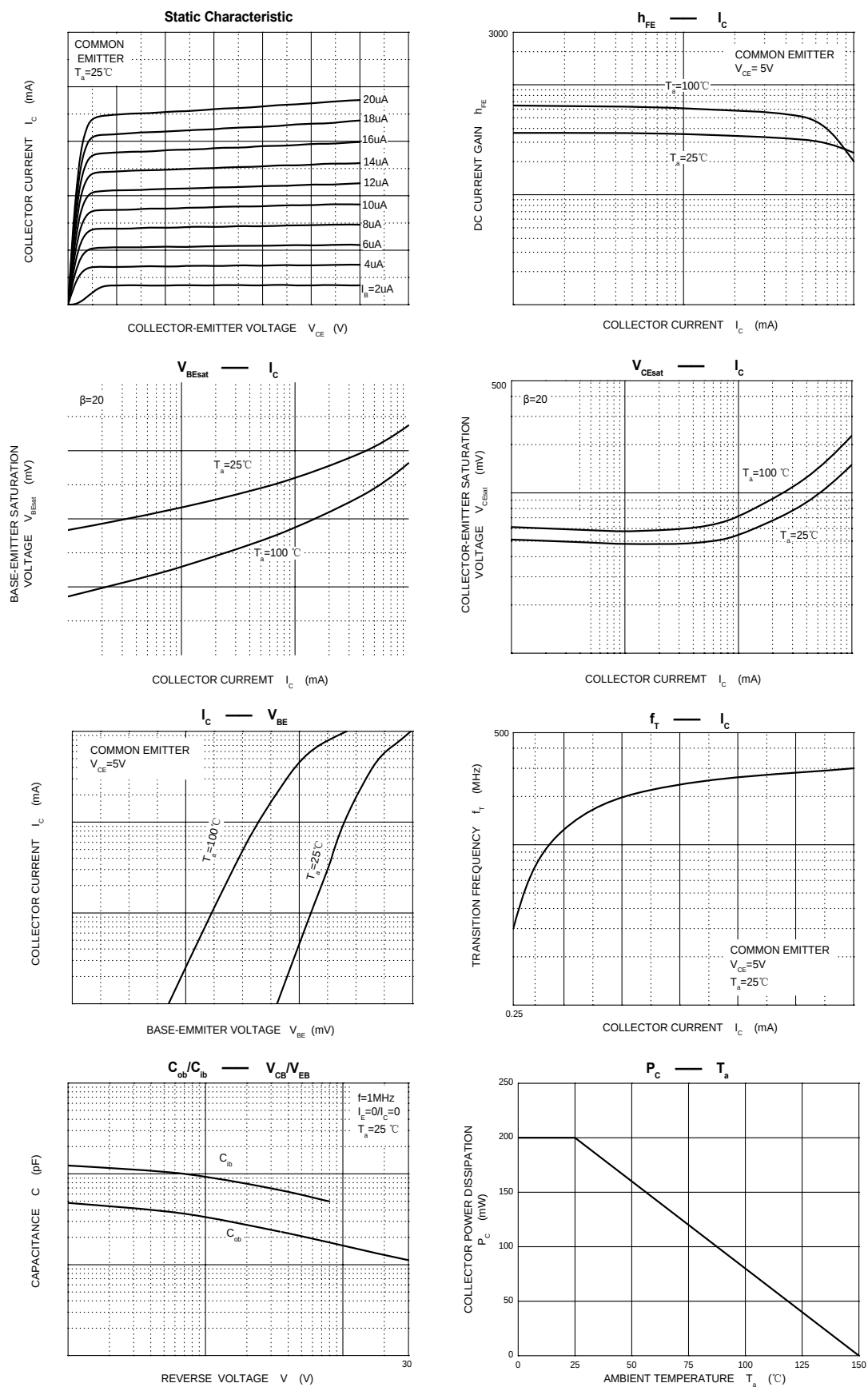
Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	-50	V
V_{CEO}	Collector-Emitter Voltage	-45	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_{C}	Collector Current –Continuous	-0.1	A
P_{C}	Collector Power Dissipation	200	mW
T_{J}	Junction Temperature	150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-55-150	$^{\circ}\text{C}$

CHARACTERISTICS of TR2 (PNP Transistor) ($T_a=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	$I_{\text{C}}=-10\mu\text{A}, I_{\text{E}}=0$	-50			V
Collector-emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	$I_{\text{C}}=-10\text{mA}, I_{\text{B}}=0$	-45			V
Emitter-base breakdown voltage	$V_{(\text{BR})\text{EBO}}$	$I_{\text{E}}=-1\mu\text{A}, I_{\text{C}}=0$	-5			V
Collector cut-off current	I_{CBO}	$V_{\text{CB}}=-30\text{V}, I_{\text{E}}=0$			-15	nA
Emitter cut-off current	I_{EBO}	$V_{\text{EB}}=-5\text{V}, I_{\text{C}}=0$			-15	nA
DC current gain	h_{FE1}	$V_{\text{CE}}=-5\text{V}, I_{\text{C}}=-2\text{mA}$	220		475	
Collector-emitter saturation voltage	$V_{\text{CE(sat)}}$	$I_{\text{C}}=-10\text{mA}, I_{\text{B}}=-0.5\text{mA}$			-0.3	V
	$V_{\text{CE(sat)}}$	$I_{\text{C}}=-100\text{mA}, I_{\text{B}}=-5\text{mA}$			-0.65	V
Base-emitter saturation voltage	$V_{\text{BE(sat)}}$	$I_{\text{C}}=-10\text{mA}, I_{\text{B}}=-0.5\text{mA}$		-0.7		V
	$V_{\text{BE(sat)}}$	$I_{\text{C}}=-100\text{mA}, I_{\text{B}}=-5\text{mA}$			-0.95	V
Base-emitter voltage	$V_{\text{BE(on)}}$	$V_{\text{CE}}=-5\text{V}, I_{\text{C}}=-2\text{mA}$	-0.6		-0.75	V
	$V_{\text{BE(on)}}$	$V_{\text{CE}}=-5\text{V}, I_{\text{C}}=-10\text{mA}$			-0.82	V
Collector output capacitance	C_{ob}	$V_{\text{CB}}=-10\text{V}, I_{\text{E}}=0, f=1\text{MHz}$			4.5	pF
Transition frequency	f_{T}	$V_{\text{CE}}=-5\text{V}, I_{\text{C}}=-10\text{mA}, f=100\text{MHz}$	100			MHz
Noise figure	NF	$V_{\text{CE}}=-5\text{V}, I_{\text{C}}=-0.2\text{mA},$ $f=1\text{kHz}, R_{\text{g}}=2\text{K}\Omega, \Delta f=200\text{Hz}$			10	dB

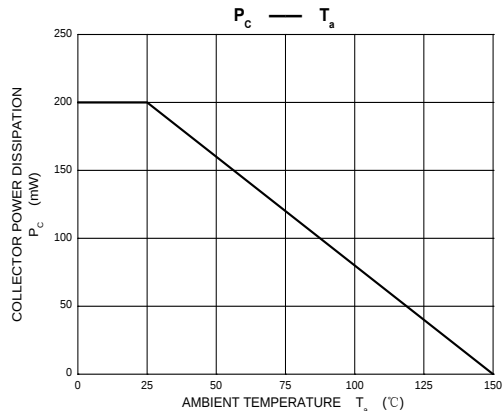
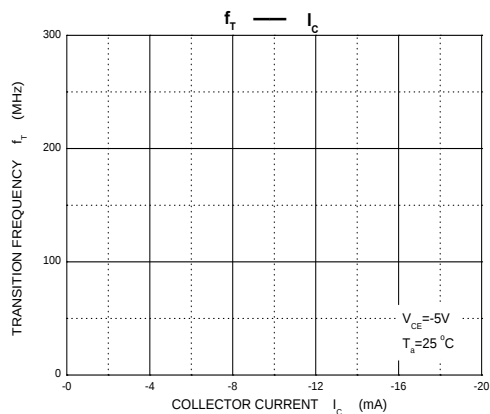
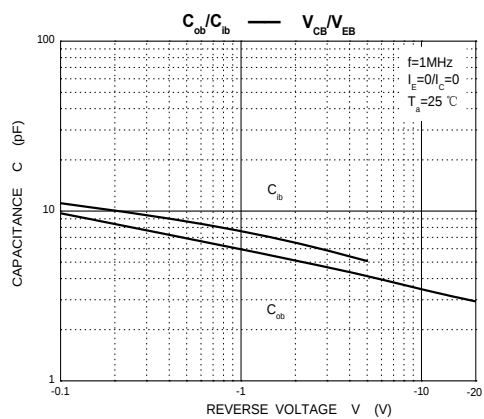
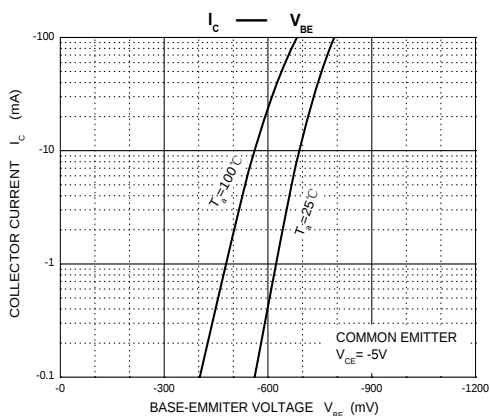
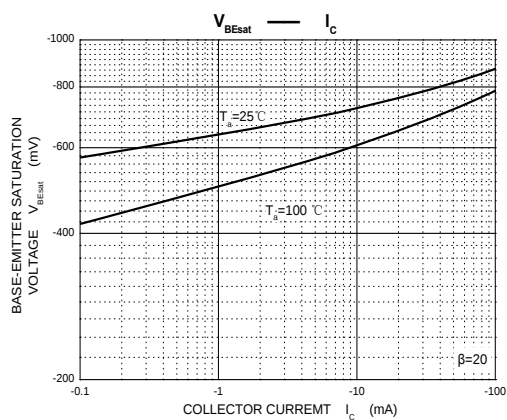
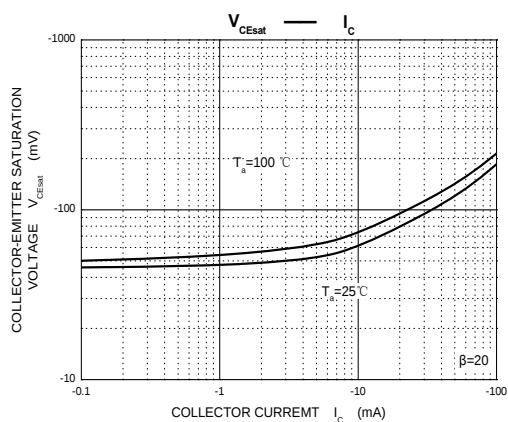
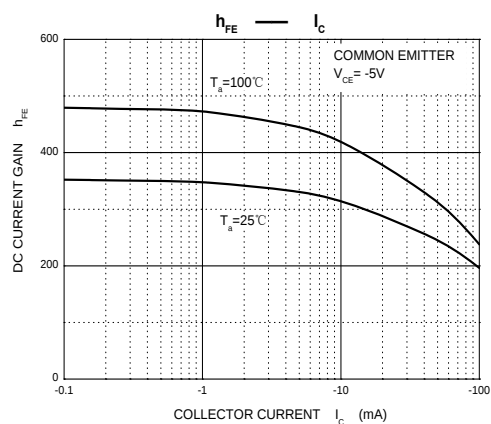
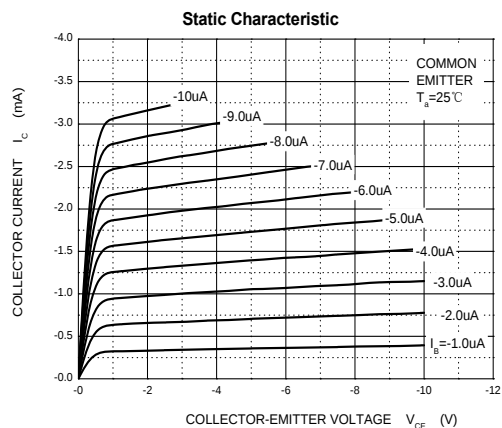


Typical Characteristics



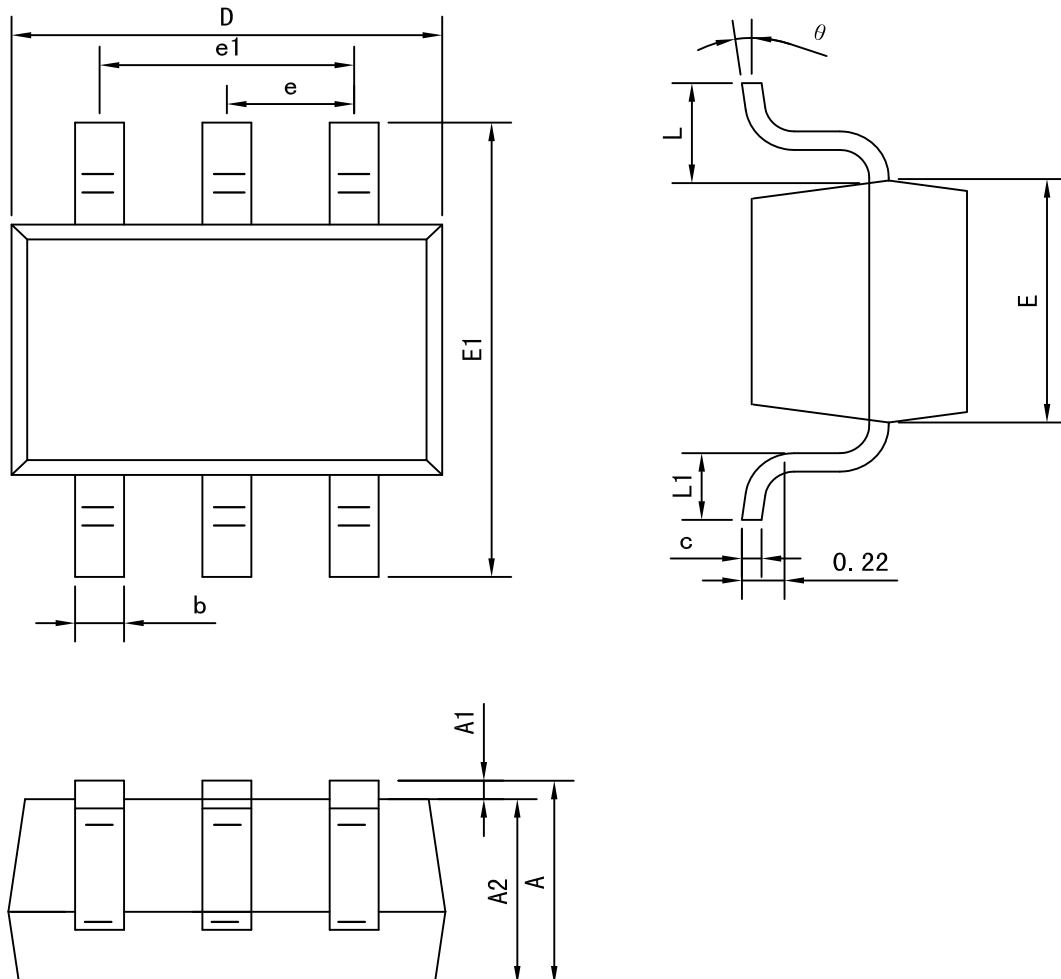


Typical Characteristics





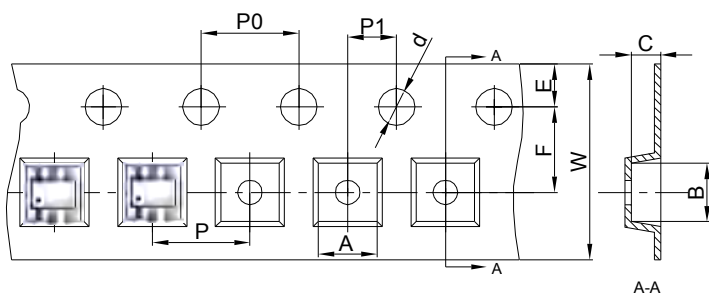
SOT-363 Package outline dimensions



Symbol	Dimension in Millimeters	
	Min	Max
A	0.900	1.100
A1	0.000	0.100
A2	0.900	1.000
b	0.150	0.350
c	0.080	0.150
D	2.000	2.200
E	1.150	1.350
E1	2.150	2.450
e	0.650 TYP	
e1	1.200	1.400
L	0.525 REF	
L1	0.260	0.460
θ	0°	8°



SOT-363 Embossed Carrier Tape



Packaging Description:

SOT-363 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-363	2.25	2.55	1.20	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-363 Tape Leader and Trailer

